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Transceiver Supports 8 × 8 MIMO Systems

Suitable for user equipment or in base transceiver stations, this RF transceiver supports wireless communications systems as large as 8×8 MIMO configurations.

odern communications systems are often judged by their data rates. Organizations such as the International Telecommunication Union (ITU; www.itu. int) suggest by their definitions that nextgeneration mobile-communications systems should operate at rates to 100 Mb/s for high-mobility operation and 1 Gb/s for low-mobility operation. So far, third-generation (3G) communications networks and their more advanced successors, such as 3.5G networks, can support data rates to several megabits per second.¹⁻⁴

Of course, modern communications users will want even faster data rates as

part of fourth-generation (4G) wireless networks. In China, for example, time-division, long-term-evolution (TD-LTE) wireless technology in the 2.6-GHz spectrum (2500 to 2690 MHz) using time-division-duplex (TDD) techniques offers the promise of high data rates in wireless communications.

In many ways, with its application of orthogonal-frequency-



2. This block diagram represents a typical superheterodyne transceiver.

Power support

1. This block diagram shows the main functions of a radio-over-fiber (RoF) system. division-multiplexing/frequency-division-multiple-access (OFDM/FDMA) technology, 3GPP LTE networks have been considered "Quasi 4G" systems. In other words, they apply 4G technologies to 3G systems for improved performance, including the use of multiple-input, multiple-output (MIMO) antenna techniques. The use of these advanced technologies allow 3G networks to achieve data rates of 100 Mb/s on downlinks and 50 Mb/s on uplinks.^{5,6}

The current transceiver was developed as part of a project for a next-generation wireless communications system for use in radio-over-fiber (RoF) applications. The transceiver supports 8 × 8 MIMO

use in user-equipment (UE) and base-transceiver-station (BTS) equipment. The transceiver's output is designed for connection to an optical transceiver and front amplifier unit (FAU). *Figure 1* shows a block diagram of the full system.

Transceiver architectures typically rely on either zero-intermediate-frequency (zero-IF) or superheterodyne configura-

> tions. Zero-IF approaches have been widely used in personal mobile devices due to their low cost and practical application as single-chip devices.^{7,8} The current transceiver design is based on the superheterodyne approach, even though it is somewhat bulky and costly.

> Each transceiver consists of several main parts, including a transmitter cir-

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TDD Transceiver



3. This photograph shows one of the transceiver's eight channels.

cuit, receiver circuit, local-oscillator (LO) module, and control circuit. *Figure 2* shows a simplified block diagram. The whole system operates in the TDD scheme. Therefore, a RF switch controlled by transmit/receive (T/R) switch signal ensures that the system can be switched between transmit and receive states.

The switching time must be short enough to meet the standards of TDD-LTE systems, or it may affect the first few symbols used for channel estimation. The decoupling capacitors of some key devices and the resistive-capacitive (RC) network of the RF switch should be designed carefully. The T/R switch signal is also used to control four other switches used in the transmitter and receiver circuits, maintaining high isolation between the two circuits.

In contrast to many conventional superheterodyne systems, the baseband output of this system is a 185-MHz digital IF signal. At baseband, the signal is sampled at digital IF with a higher sample rate to help avoid potential problems. A baseband anti-aliasing filter can provide

much better performance in the digital domain compared to an analog filter.

The transceiver's transmitter consists of several amplifiers, an IF/RF filter, a mixer, digital attenuators, and switches. Because the signal from baseband remains components should be carefully designed to achieve the required transmit performance parameters, including output power, linearity, and spurious suppression. For example, an LTE signal must have high peak-to-average power ratio (PAPR), especially with complex modulated signals reaching 8 dB or higher.

constant, the transmitter's output power is changed by

means of two digital

attenuators which

work in conjunc-

tion with several

small-signal ampli-

fiers and one power

amplifier to achieve

desired transmit

power levels. These

The receiver circuitry—with its lownoise amplifier (LNA) IF/RF filter, mixer, digital attenuators, switches, and smallsignal amplifiers—is somewhat similar in architecture to the transmitter circuitry, differing in its dynamic range. The receiver circuitry should not only provide enough gain for small signals, but also avoid amplifier saturation for large signals. As a result, gain control is an important function for the receiver circuitry.

The gain control is achieved via several gain blocks and two digital attenuators for 64-dB total gain control with 0.5-dB gain control per step. The passive mixer is used to convert RF signals to the IF stage. As with the transmitter, the layout and device selection for the receiver circuitry should be carefully considered to



4. This block diagram details the main functions in the RF transceiver system.



5. These measurements show the LO phase noise at 965 MHz (left) and 1450 MHz (right).

achieve desired linearity and spurious suppression.

Each channel of the transceiver was designed on a four-layer FR-4-based printed-circuit board (PCB) with relative dielectric constant (ϵ_r) of 4.6 to achieve small size and low cost. System-level transceiver simulation was performed with the ADS 2009 Advanced Design System (ADS) simulation software from Agilent Technologies (www.agilent.com). To avoid possible interference between function modules, each RF board was designed and assembled with several metal compartments for isolation. This metal framework with covers was indispensable for achieving good electromagnetic-interference (EMI) shielding. *Figure 3* shows one of the transceiver channels.

For general-purpose use, all of the transceiver's control signals are realized by a single-chip complex programmable logic device (CPLD), and all eight transceiver channels can be controlled and synchronized separately through the backboard. The system requires a frequency synthesizer control signal and reference clock for the synthesizer's phase lock loop (PLL). Since the quality of the reference oscillator is closely tied to the oscillator phase noise, the amplitude, waveform quality, and jitter of the reference oscillator are important parameters in the system design.

The transceiver system's power board provides DC-to-DC conversion from +48 VDC to +6 VDC for the system. The control board acts as an interface between the baseband control signal and the RF board's control operation. It includes power and gain control for each transmitter and receiver, respectively, along with other functions like reference clock calibration.

The reference board provides an accurate 10-MHz reference clock which is generated by an oven-controlled crystal oscillator (OCXO). A PLL circuit is carefully designed to lock and track a 30.72-MHz Global-Positioning-System (GPS) reference clock from baseband quickly, even if the OCXO has a very slight change due to an external disturbance.

The full transceiver system includes eight RF boards, one backboard, one power board, one control board, and one ref-

erence board (*Fig. 4*). The performance of the transceiver was evaluated with commercial test equipment from some of the top suppliers. A model N5767A power supply from Agilent, for example, provides the full system's +48 VDC voltage, while models E4438C and N5182 signal generators and a model N9030 signal analyzer from the firm were also used in the testing.

A model FSUP50 signal source analyzer from Rohde & Schwarz (www.rohde-schwarz.com), with available models to 26.5 GHz, was also used as part of the test system to check LO phase noise. The LO module is designed to provide low-phase-noise signals, providing IF LO signals at 965 MHz and RF LO signals at 1.45 GHz.

Figure 5 shows the phase-noise performance of the LO module, revealing that the phase noise of the IF LO is slightly better than the phase noise of the RF LO. According to the test results, the phase noise of the RF LO is better than -93 dBc/ Hz offset 10 kHz from the carrier, while the phase noise of the IF LO is better than -96 dBc/Hz offset 10 kHz from the carrier. The low phase noise is due to the careful design of LO's power



6. These plots show the transmitter's output power and linearity.

supply, where an appropriate decoupling capacitor is essential.

For each transmit channel, output power, linearity, and gain flatness are key performance parameters. Across the full 100-MHz bandwidth of the transmit channel, gain fluctuation is less than 1 dB. This is due to careful design and tuning to achieve optimum impedance matches between difference devices and circuit layouts. The maximum output power of each channels is about +23 dBm, with third-order intermodulation (IMD3) held as low as -53 dBc (tested with a two-tone signal with 1-MHz spacing). As *Fig.* 6 shows, each transmitter channel achieves good linearity.

Another means of evaluating the transceiver's linearity and spectral spreading between the main channel (useful signal) and adjacent channel (intermodulation signal) is by ACPR testing and analysis, especially in modern wireless communications systems. For output power of +23 dBm, the transceiver's ACPR is less than -49 dBc. The evaluation was performed with 64-state quadrature-amplitude-modulation (64QAM) signals, with a reference bandwidth of 20 MHz and reference offset of 5 MHz (*Fig. 7*).

Unlike the transmit channel, the receive channel requires a stable output power level of around -10 dBm and IMD3 of better than -50 dBc for the baseband over a wide power range in spite of the power of the received signal. Gain fluctuation for each receiver channel is less than 1.5 dB in a 100-MHz bandwidth-slightly larger than that of the transmitter due to the ripple of two IF cavity filters. Still, this performance level can be tolerated since multicarrier modulation is often used in modern systems. It is also difficult to use a 100-MHzbandwidth single-carrier modulation technique for TDD-LTE signals in a wireless communication system.

The error-vector-magnitude (EVM) parameter was used to appraise the whole system's performance, since it provides information on some key system perfor-

SUMMARIZING EVM PERFORMANCE (IN dB) PER CHANNEL								
Channel	1	2	3	4	5	6	7	8
Transmit	2.28	2.17	2.14	1.74	1.98	1.93	1.63	1.70
Receive	2.07	2.01	2.14	2.07	1.83	1.74	1.80	1.85

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TDD Transceiver



7. The transmitter's ACPR is plotted at a center frequency of 2.6 GHz.

mance levels, including amplitude/phase imbalance, gain compression/flatness, and phase noise. EVM measurements were performed with the aid of a model N9030A PXI signal analyzer from Agilent and the company's model 89600A vectorsignal-analyzer (VSA) software. Due to the limits of the available test equipment, the maximum symbol rate used for testing was 20 MHz.

The test signals include 16QAM, 64QAM, and TDD-LTE characteristics. Characterization of the test system includes test cables with insertion loss of 3.3 dB at 2.6 GHz. The measured EVM levels for 16QAM and 64QAM signals were both less than 0.9% while the trans-



8. These spectra and error summaries represent the transmitter (left) and receiver (right) performance.

ceiver works without switching, which is excellent performance. The spectra of the transmitter and receiver deteriorate somewhat with switching, as depicted in Fig. 8 for TDE-LTE test signals.

The table summarizes the performance levels for all eight

transceiver channels. The slight differences among these channels and the EVM of the transmit/receive signals is around 1.7% to 2.3%. The transceiver was tested with continuous switching between transmit and receive states under the control of the N7625B signal studio software and the E4438C signal generator.

According to the design procedure and test results, one phenomenon should be pointed out. This TDD system consists of as much as eight transceivers, and its current can fluctuate considerably when switching between transmit and receive modes. For example, the system's current is about 13 A when the transmit state is on and 4 A when the transmit state is off.

> With only one +48-VDC power supply for the full system, the DC power's current fluctuation may influence the LO module's performance. One phenomenon is the EVM will deteriorate at a rapid pace, particularly the constellation rotation, which is an intimation of poor phase noise (Fig. 9, *left*). The distortion of the constellation's magnitude is evident (Fig. 9, left).

Some applications require proper decoupling and active



9. These constellation diagrams show the transceiver with untreated (left) and treated (right) DC power.

filter circuit for each transceiver's LO module and the reference board's power supply has been adopted and carefully designed in this eight-channel MIMO system. According to *Fig. 9 (right)*, which shows a TDD-LTE constellation with treated power, the EVM deteriorates seriously only during the first several symbols in less than 1 μ s, and then a stable constellation is achieved. This is in contrast to the EVM for untreated power *(Fig. 9, left)*.

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